LDMOS 3-stage integrated Doherty MMIC

Rev. 1 — 14 December 2020

1. Product profile

1.1 General description

The BLM10D3740-35AB is a 3-stage fully integrated asymmetrical Doherty MMIC solution using Ampleon's state of the art LDMOS technology. The carrier and peaking device, input splitter, output combiner and pre-match are integrated in a single package. This multiband device is perfectly suited as a final stage for small cells and massive MIMO applications in the frequency range from 3700 MHz to 4000 MHz. Available in PQFN outline.

Table 1. Application performance

Typical RF performance at $T_{case} = 25 \ ^{\circ}C$; $I_{Dq} = 44 \ mA$ (carrier); $V_{GSq(peaking)} = V_{GSq(carrier)} - 0.5 \ V$. Test signal: 1-carrier LTE 20 MHz; PAR = 7.6 dB.

Test signal	f	V _{DS}	P _{L(AV)}	G _p	η
	(MHz)	(V)	(W)	(dB)	(%)
single carrier LTE	3900	28	5	33	39

1.2 Features and benefits

- Integrated input splitter
- Integrated output combiner
- **30** Ω output impedance thanks to integrated pre-match
- Very high efficiency thanks to asymmetry
- Designed for wideband operation (frequency 3700 MHz to 4000 MHz)
- Independent control of carrier and peaking bias
- Integrated ESD protection
- Source impedance 50 Ω ; high power gain
- For RoHS compliance see the product details on the Ampleon website

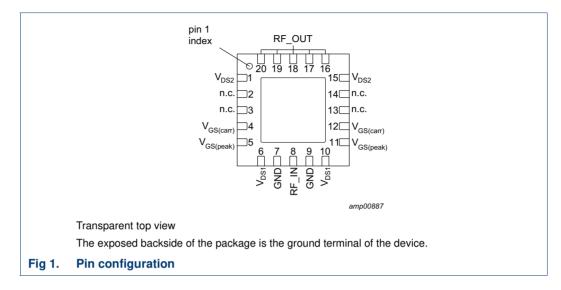
1.3 Applications

 RF power MMIC for multi-carrier and multi-standard 5G base stations in the 3700 MHz to 4000 MHz frequency range

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2. Pinning information

2.1 Pinning



2.2 Pin description

Table 2. Pin descri	Table 2. Pin description				
Symbol	Pin	Description			
V _{DS2}	1	drain-source voltage of final stages			
n.c.	2	not connected			
n.c.	3	not connected			
V _{GS(carr)}	4	gate-source voltage of carrier			
V _{GS(peak)}	5	gate-source voltage of peaking			
V _{DS1}	6	drain-source voltage of driver stages			
GND	7	RF ground			
RF_IN	8	RF input			
GND	9	RF ground			
V _{DS1}	10	drain-source voltage of driver stages			
V _{GS(peak)}	11	gate-source voltage of peaking			
V _{GS(carr)}	12	gate-source voltage of carrier			
n.c.	13	not connected			
n.c.	14	not connected			
V _{DS2}	15	drain-source voltage of final stages			
RF_OUT	16	RF output			
RF_OUT	17	RF output			
RF_OUT 18 RF output		RF output			
RF_OUT	RF_OUT 19 RF output				
RF_OUT	RF_OUT 20 RF output				
GND	flange	RF ground			

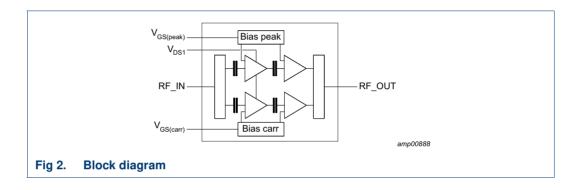
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3. Ordering information

Table 3. Ordering i	nformation		
Type number	Package		
	Name	Description	Version
BLM10D3740-35AB	PQFN20	plastic thermal enhanced quad flat package; no leads; 20 terminals; body 8.0 x 8.0 x 2.1 mm	SOT1462-1

4. Block diagram



5. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{DS}	drain-source voltage		-	65	V
V _{GS}	gate-source voltage		-0.5	+13	V
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature	[1]	-	200	°C

[1] Continuous use at maximum temperature will affect the reliability. For details refer to the online MTF calculator.

6. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Value	Unit
R _{th(j-c)}	thermal resistance from junction to case	$T_{case} = 90 \ ^{\circ}C; P_{L} = 2 \ W$ [1]	4	K/W
		$T_{case} = 90 \ ^{\circ}C; P_{L} = 5 \ W$ [1]	3.2	K/W

[1] When operated with a 1-carrier W-CDMA with PAR = 7.6 dB.

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Characteristics 7.

Table 6. DC characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Carrier						
V _{GSq}	gate-source quiescent voltage	$V_{DS} = 28 \text{ V}; I_D = 42 \text{ mA}$	1.65	2.0	2.6	V
I _{GSS}	gate leakage current	$V_{GS} = 1 V; V_{DS} = 0 V$	-	-	140	nA
Peaking		1				
I _{GSS}	gate leakage current	$V_{GS} = 1 V; V_{DS} = 0 V$	-	-	140	nA
Final st	ages	1				
I _{DSS}	drain leakage current	$V_{GS} = 0 V; V_{DS} = 28 V$	-	-	1.4	μA
Driver s	tages	1				
I _{DSS}	drain leakage current	$V_{GS} = 0 V; V_{DS} = 28 V$	-	-	1.4	μA

Table 7. **RF Characteristics**

Typical RF performance at $T_{case} = 25 \ ^{\circ}C$; $V_{DS} = 28 \ V$; $I_{Dq} = 42 \ mA$ (carrier); $V_{GSq(peaking)} = V_{GSq(carrier)} - 0.5 \ V$; $P_{L(AV)} = 5 \ W$; $f = 3850 \ MHz$ measured in an Ampleon production device interface board.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Test sigr	nal: single carrier pulsed CW [1]					
G _p	power gain	P _L = 5 W (37 dBm)	32.2	34.2	36.4	dB
η _D	drain efficiency	P _L = 5 W (37 dBm)	34	41	-	%
		$P_{L} = P_{L(3dB)}$	41	47	-	%
RL _{in}	input return loss		-	-	-10	dB
P _{L(3dB)}	output power at 3 dB gain compression		44.7	45.2	-	dBm

[1] Pulsed CW power sweep measurement (δ = 10 %, t_p = 100 µs).

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8. Application information

Table 8. Typical performance

 $T_{case} = 25 \text{ °C}; V_{DS} = 28 \text{ V}; I_{Dq} = 44 \text{ mA} (carrier); V_{GSq(peaking)} = V_{GSq(carrier)} - 0.5 \text{ V}.$ Test signal: 1-carrier LTE; PAR = 7.6 dB at 0.01 % probability CCDF; unless otherwise specified, typical performance in an Ampleon f = 3700 MHz to 4000 MHz frequency band application circuit.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
P _{L(3dB)}	output power at 3 dB gain compression	f = 3900 MHz	[1]	-	45.4	-	dBm
$\phi_{s21}/\phi_{s21(norm)}$	normalized phase response	at 3 dB compression point; f = 3900 MHz			-26	-	0
η _D	drain efficiency	8 dB OBO (P _{L(AV)} = 37 dBm); f = 3900 MHz			39	-	%
G _p	power gain	P _{L(AV)} = 37 dBm; f = 3900 MHz		-	33.1	-	dB
B _{video}	video bandwidth	P _{L(AV)} = 37 dBm; 2-tone CW; f = 3800 MHz		-	420	-	MHz
G _{flat}	gain flatness	P _{L(AV)} = 37 dBm; f = 3700 MHz to 4000 MHz		-	1.9	-	dB
ACPR _{20M}	adjacent channel power ratio (20 MHz)	P _{L(AV)} = 37 dBm; f = 3900 MHz		-	-31	-	dBc
$\Delta G / \Delta T$	gain variation with temperature	f = 3900 MHz	[3]	-	0.07	-	dB/°C
$\Delta P_{L(3dB)} / \Delta T$	output power at 3 dB gain compression variation with temperature	f = 3900 MHz [1]		-	0.016	-	dBm/°C
К	Rollett stability factor	$T_{case} = -30 \text{ °C}; f = 0.1 \text{ GHz to}$ 6.1 GHz	<u>[3]</u>	-	>1	-	

[1] Pulsed CW power sweep measurement (δ = 10 %, t_p = 100 µs).

[2] 25 ms CW power sweep measurement.

[3] S-parameters.

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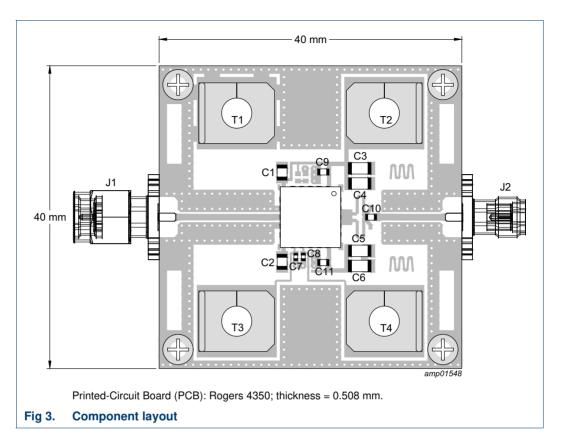
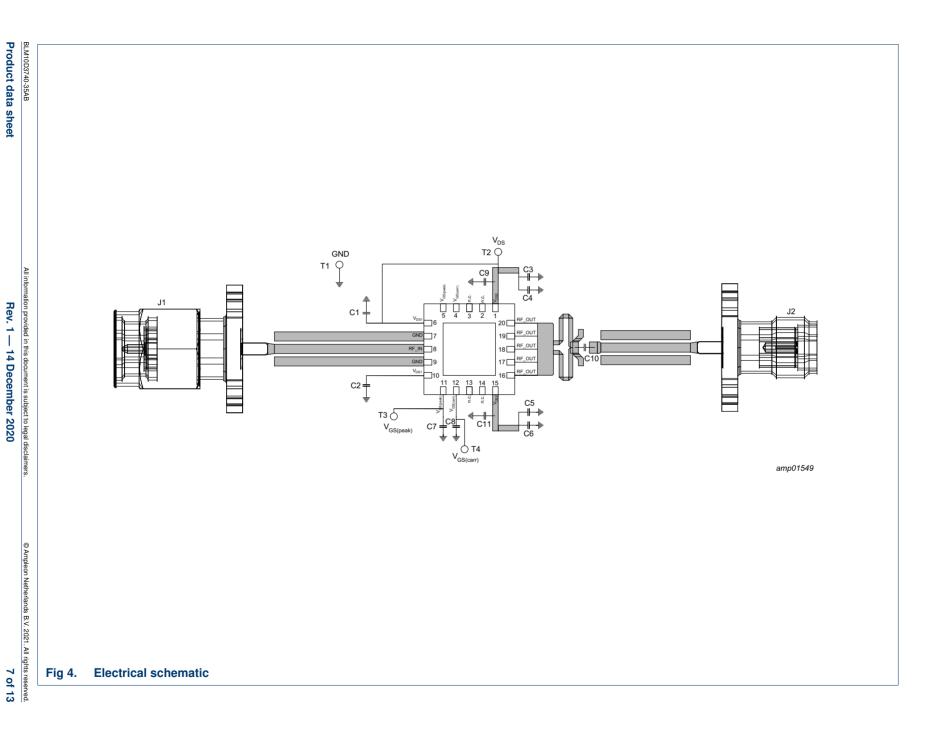


Table 9. Demo test circuit list of components

See Figure 3 for component layout.

Component	Description	Value	Remarks
C1, C2	multilayer ceramic chip capacitor	10 μF, 6.3 V	Murata: GRM21BR60J106KE01L
C3, C4, C5, C6	multilayer ceramic chip capacitor	10 μF, 50 V	Murata: GRM31CR61H106KA12L
C7, C8	multilayer ceramic chip capacitor	4.7 μF, 6.3 V	Murata: GRM155R60J475ME47D
C9	multilayer ceramic chip capacitor	3.3 pF ± 0.1 %	Murata: GQM1875C2E3R3BB12
C10	multilayer ceramic chip capacitor	3 pF ± 0.1 %	Murata: GQM1875C2E3R0BB12
C11	multilayer ceramic chip capacitor	3 pF ± 0.1 %	Murata: GQM1875C2E3R0BB12
J1	SMA Coaxial panel connector male		Huber & Suhner: 13_SMA-50-0-2/111_N
J2	SMA Coaxial panel connector female		Huber & Suhner: 23_SMA-50-0-2/111_N
T1, T2, T3, T4	PCB Terminal	6.35 mm × 0.81 mm, 4.1 mm	TE connectivity

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8.1 Ruggedness in a Doherty operation

The BLM10D3740-35AB is capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions: V_{DS} = 32 V; I_{Dq} = 45 mA (carrier); $V_{GSq(peaking)} = V_{GSq(carrier)} - 0.5$ V; P_i corresponding to $P_{L(3dB)} - 5$ dB under Z_S = 50 Ω load; f = 3800 MHz (1-carrier W-CDMA; PAR = 9.9 dB); T_{case} = 25 °C.

8.2 Impedance information

Table 10. Typical impedance for optimum Doherty operation

Measured load-pull data; test signal: pulsed CW; $T_{case} = 25 \text{ °C}$; $V_{DS} = 28 \text{ V}$; $I_{Dq} = 42 \text{ mA}$ (carrier); $V_{GSq(peaking)} = V_{GSq(carrier)} - 0.5 \text{ V}$; $t_p = 100 \ \mu s$; $\delta = 10 \ \%$.

	tuned for optimum Doherty operation					
f	ZL	P _{L(3dB)}	G _{p(max)}	໗ add <mark>[1]</mark>	໗ add [2]	
(MHz)	(Ω)	(dBm)	(dB)	(%)	(%)	
3600	28.06 – j2.10	45.90	34.41	48.24	39.00	
3700	23.04 – j5.66	45.88	35.68	49.89	42.17	
3800	22.77 – j7.56	45.82	35.98	51.62	43.40	
3900	22.76 – j7.54	45.61	35.02	52.61	42.71	
4000	24.82 – j5.25	45.26	32.87	51.26	38.20	
4100	19.20 – j4.72	44.79	29.92	49.13	32.16	

[1] at P_{L(3dB)}.

[2] at 37 dBm.

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9. Package outline

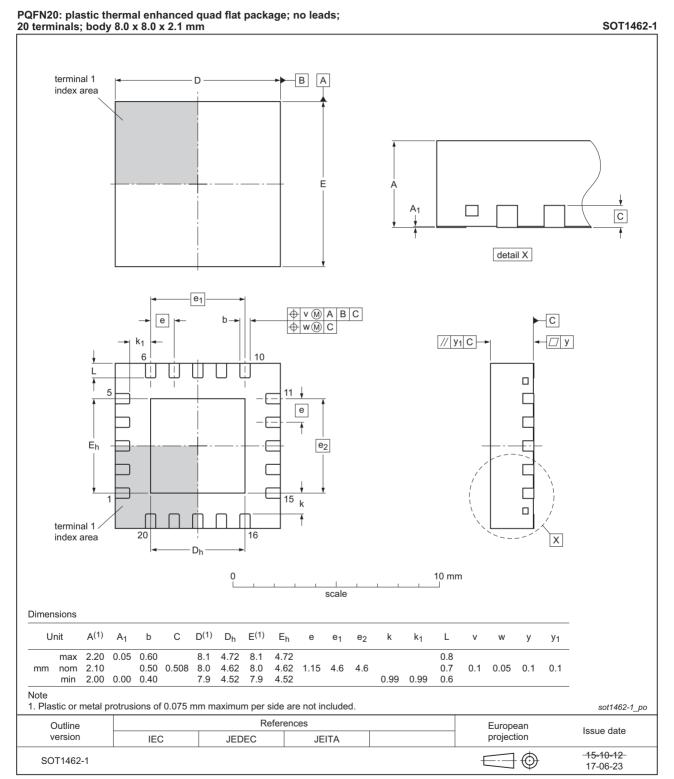


Fig 5. Package outline SOT1462-1 (PQFN20)

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10. Handling information

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the ANSI/ESD S20.20, IEC/ST 61340-5, JESD625-A or equivalent standards.

Table 11.ESD sensitivity

I	ESD model	Class
(Charged Device Model (CDM); According to ANSI/ESDA/JEDEC standard JS-002	C2A [1]
ł	Human Body Model (HBM); According to ANSI/ESDA/JEDEC standard JS-001	1B 🛛

[1] CDM classification C2A is granted to any part that passes after exposure to an ESD pulse of 500 V.

[2] HBM classification 1B is granted to any part that passes after exposure to an ESD pulse of 500 V.

11. Abbreviations

Table 12. Abbreviations					
Acronym	Description				
CCDF	Complementary Cumulative Distribution Function				
CW	Continuous Wave				
ESD	ElectroStatic Discharge				
LDMOS	Laterally Diffused Metal Oxide Semiconductor				
LTE	Long Term Evolution				
MMIC	Monolithic Microwave Integrated Circuit				
MIMO	Multiple Input Multiple Output				
MTF	Median Time to Failure				
OBO	Output Back Off				
PAR	Peak-to-Average Ratio				
RoHS	Restriction of Hazardous Substances				
VSWR	Voltage Standing Wave Ratio				
W-CDMA	Wideband Code Division Multiple Access				

12. Revision history

Table 13.Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BLM10D3740-35AB v.1	20201214	Product data sheet	-	-

13. Legal information

13.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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[2] The term 'short data sheet' is explained in section "Definitions".

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